

Supporting Information

Tailoring vanadium oxide crystal orientation for high-performance aqueous zinc-ion batteries

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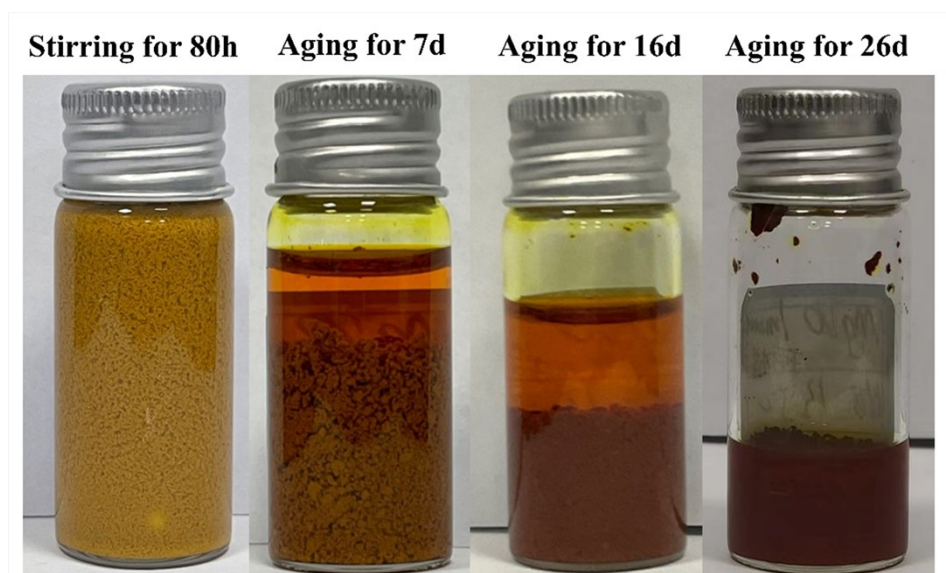


Figure S1. MgVO sample is stirred for 80h, aged for 7, 16 and 26 days respectively (Photographs taken after retrieval of samples).

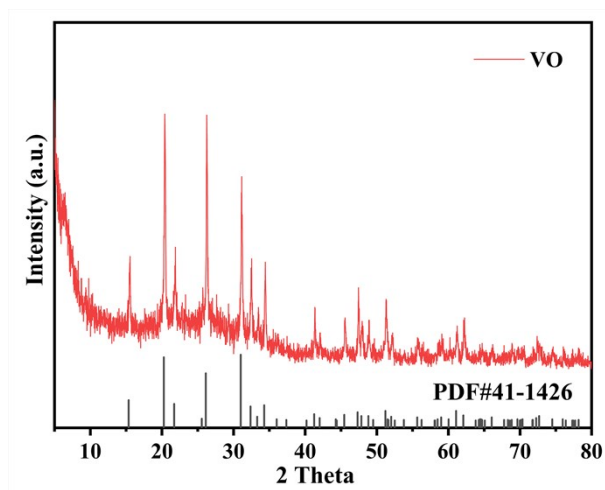


Figure S2. The XRDs of VO.

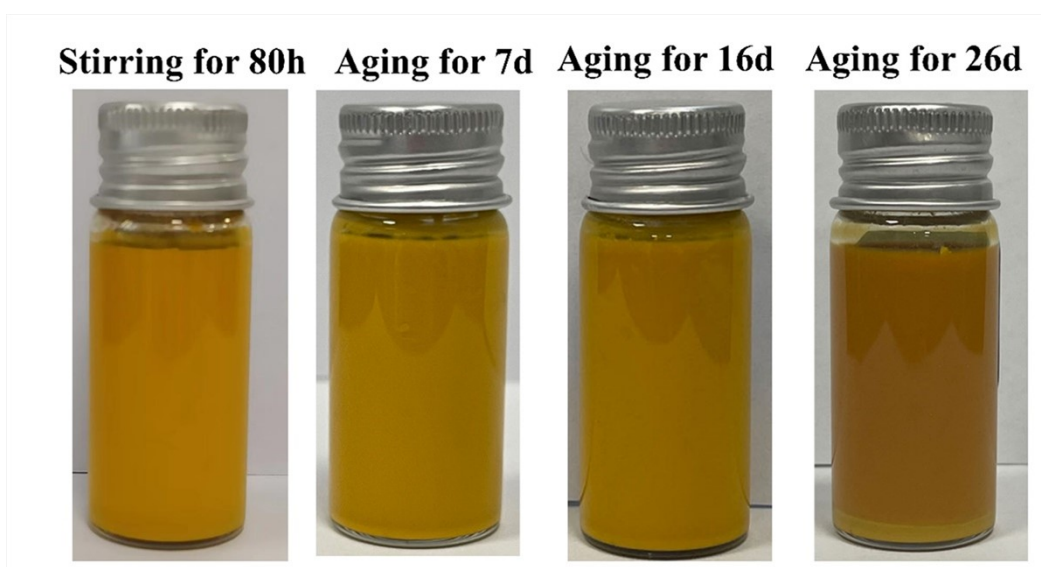


Figure S3. Commercialized V_2O_5 powder in DI water is stirred for 80h, aged for 7, 16 and 26 days respectively (Photographs taken after retrieval of samples and shaking well for the first three times and then shooting).

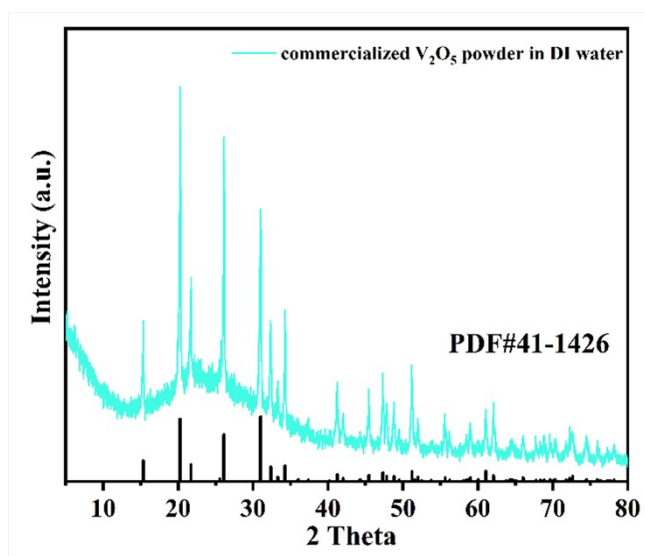


Figure S4. XRD of commercialized V_2O_5 powder in DI water sample.

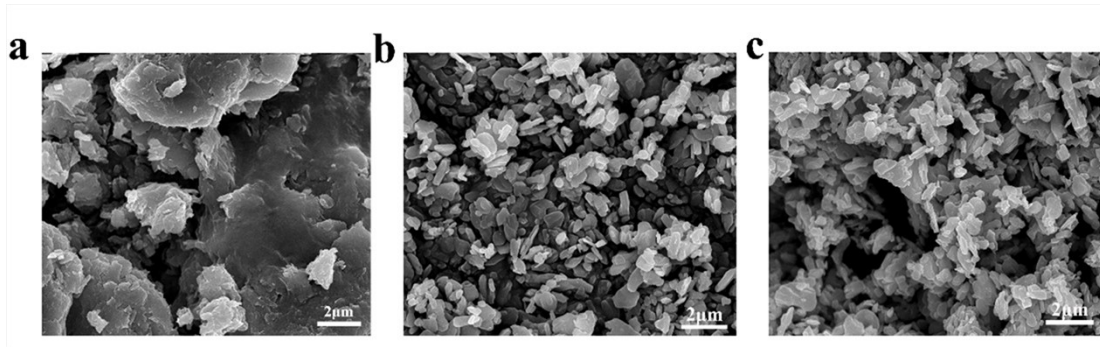


Figure S5. SEM images of VO (a), sample of commercialized V₂O₅ powder in DI water (b), and commercialized V₂O₅ powder (c).

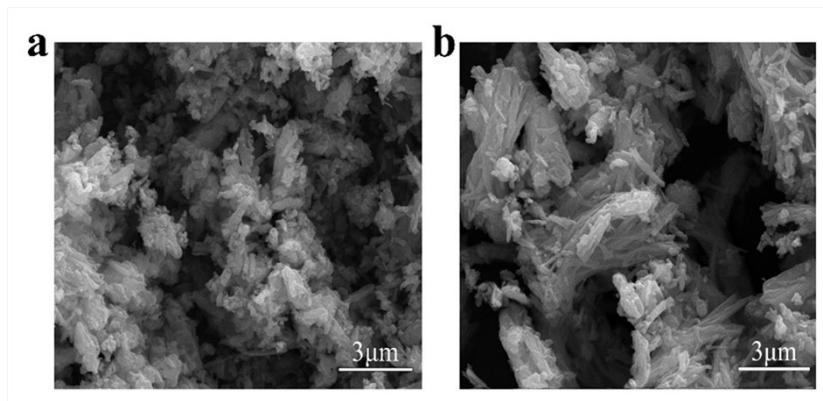


Figure S6. SEM images of MgVO I (a) and MgVO II (b).

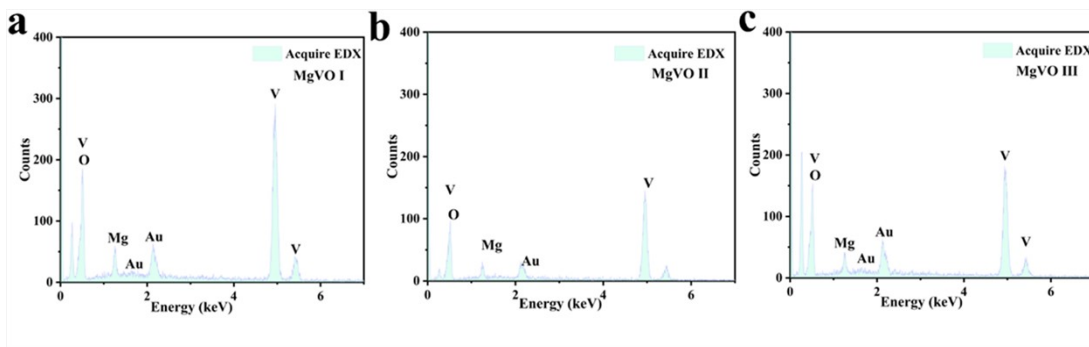


Figure S7. EDX patterns of MgVO I (a), MgVO II (b) and MgVO III (c).

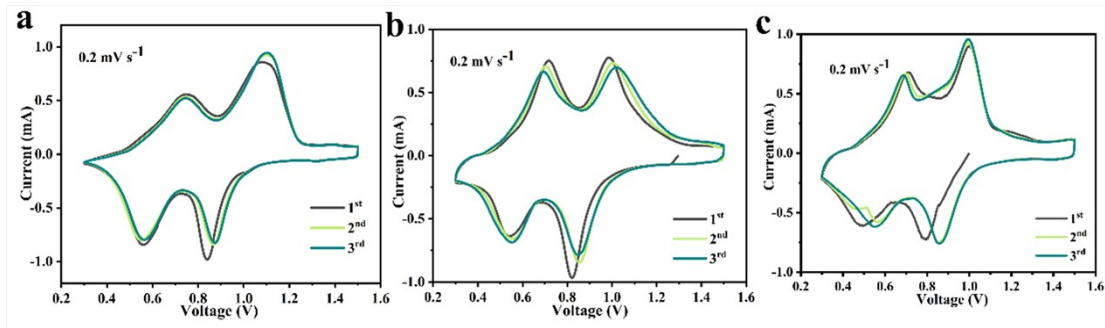


Figure S8. CV curves of MgVO at a scan rate of 0.2 mV s⁻¹: (a) VO, (b) MgVO I, (c) MgVO II.

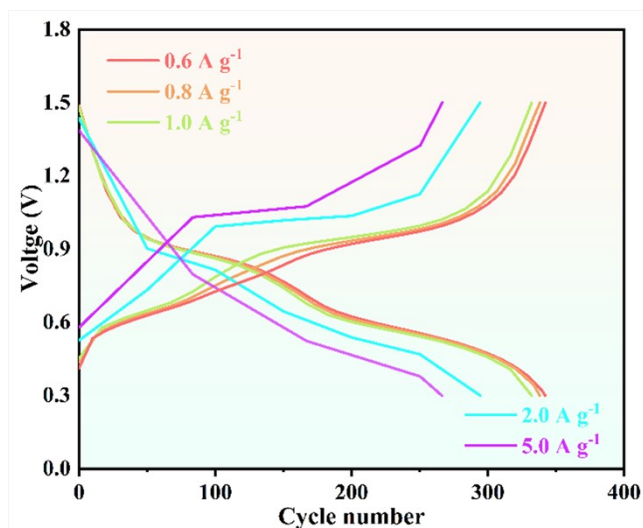


Figure S9. GCD plot of MgVO III at different current densities.

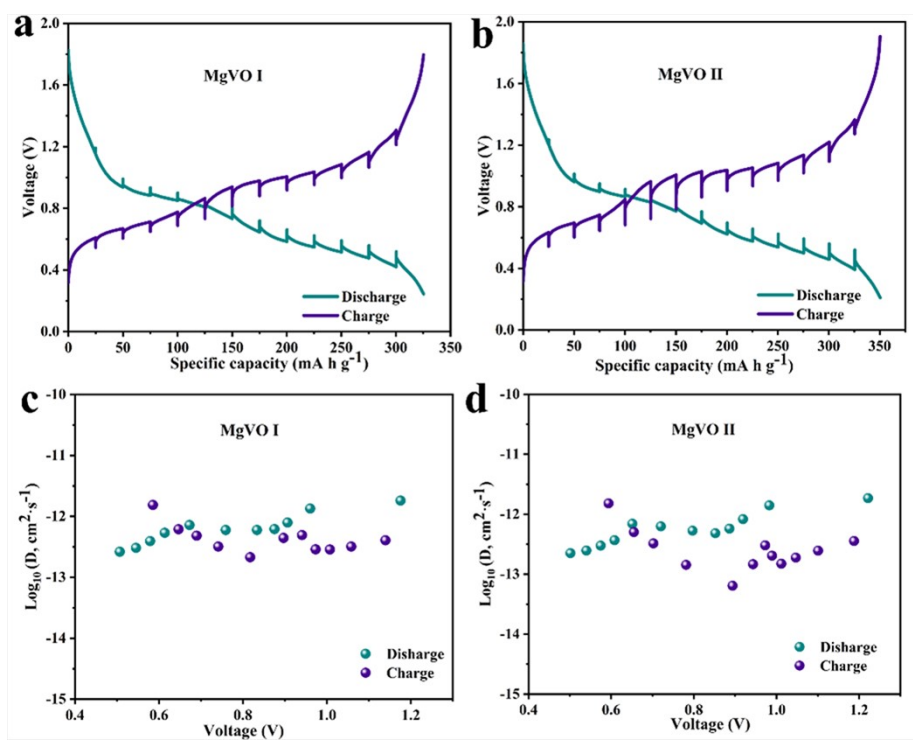


Figure S10. (a, c) Discharge-charge curve of MgVO I in the GITT measurement and the corresponding diffusivity coefficient of Zn^{2+} , (b, d) Discharge-charge curve of MgVO II in the GITT measurement and the corresponding diffusivity coefficient of Zn^{2+} .

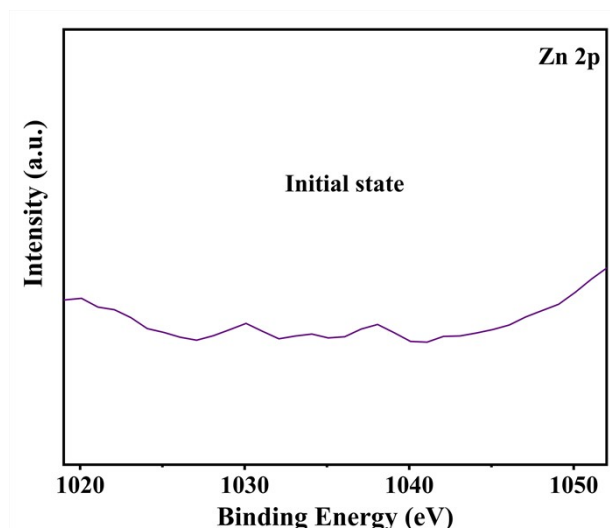


Figure S11. The XPS spectrum of MgVO III: Zn 2p.

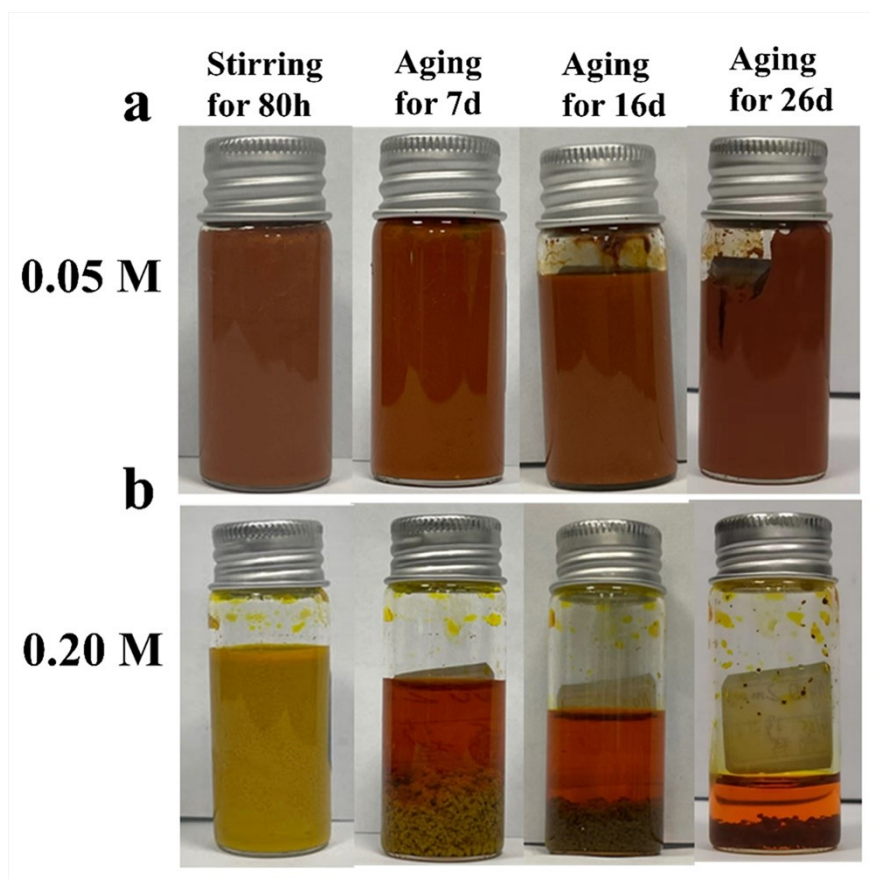


Figure S12. MgVO 0.5 (a) and MgVO 2.0 (b) samples are stirred for 80h, aged for 7, 16 and 26 days respectively (Photographs taken after retrieval of samples).

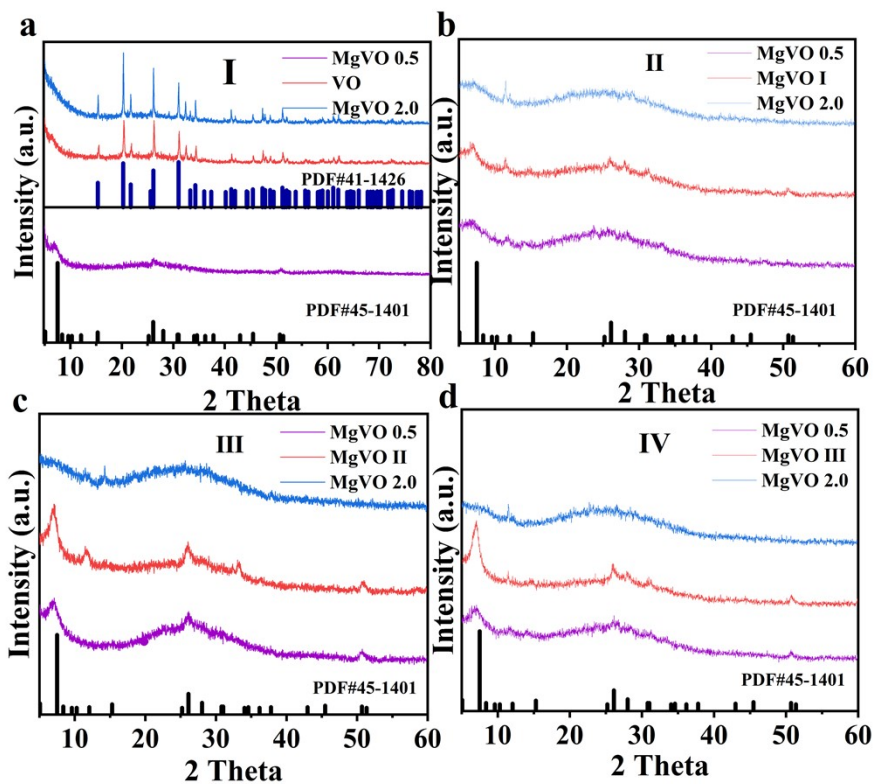


Figure S13. XRD of MgVO 0.5, MgVO, MgVO 2.0 samples: (a) stirring for 80h, (b) aging for 7 days, (c) aging for 16 days, (d) aging for 26 days.

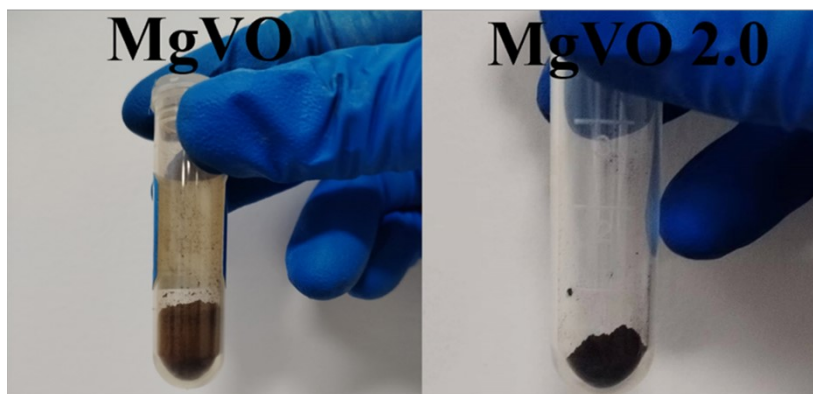


Figure S14. Powders after centrifugal drying of MgVO and MgVO 2.0.

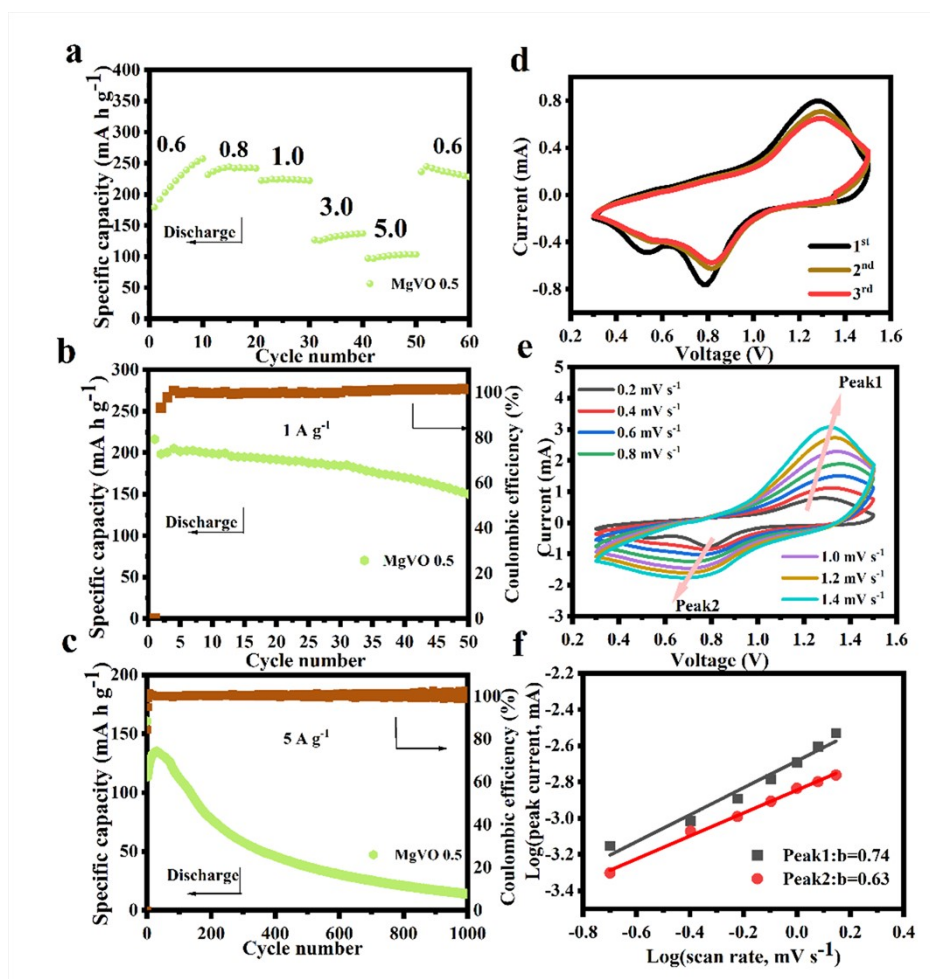


Figure S15. The electrochemical behavior of MgVO 0.5 when the cell is discharge: (a) Rate performance, (b-c) Cycling performance at a current density of 1 A g^{-1} , 5 A g^{-1} , respectively. The reaction kinetics of MgVO 0.5 (d) The CV of MgVO 0.5 in the first three cycles at 0.2 mV s^{-1} . (e) The CV of MgVO 0.5 at scan rates of 0.2 mV s^{-1} - 1.4 mV s^{-1} , and (f) $\text{Log}(i)$ vs $\text{log}(v)$ plot of MgVO 0.5.

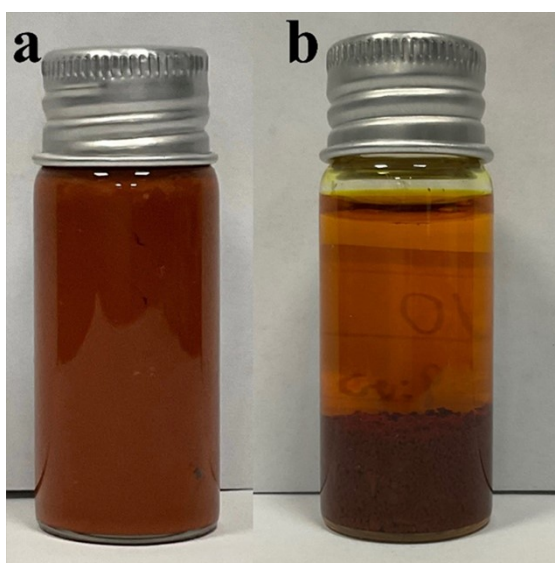


Figure S16. (a) CuVO, and (b) ZnVO sample.

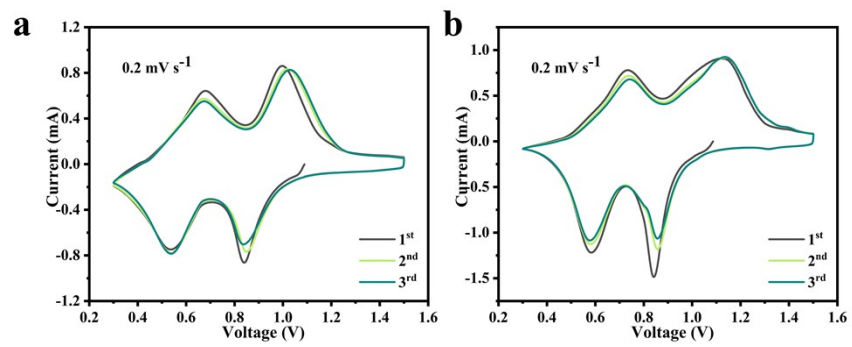


Figure S17. The first three cycles of CV curves of (a) CuVO, and (b) ZnVO at a scan rate of 0.2 mV s^{-1} .

Table S1. Texture coefficient ratio of TC₍₀₀₁₎/TC_{(MgVO III (001))}.

(001) plane	TC (%)
MgVO I (001)/MgVO III (001)	0.30
MgVO II (001)/MgVO III (001)	0.63
MgVO III (001)/MgVO III (001)	1.00

Table S2. EDX data for MgVO (I , II , III)

Sample	Element	Weight (%)	Atom (%)
MgVO I	Mg	2.80	2.60
	V	41.00	18.16
MgVO II	Mg	2.96	2.81
	V	43.04	19.46
MgVO III	Mg	2.75	2.48
	V	37.84	16.26

Table S3. ICP-MS data for MgVO III

Element	Elemental content C _x (mg/kg)	Elemental content W (%)
V	482995.95	48.300%
Mg	26356.28	2.636%

Table S4. Performance comparison of MgVO III and other vanadium-based materials

Cathode materials	Electrochemical performance	Reference
Mg _{0.57} V ₅ O ₁₂ ·2.3H ₂ O	5 A g ⁻¹ , 232.5 mA h g ⁻¹ after 1400 cycles, 94%	This work
Ba _{0.26} V ₂ O ₅ ·0.92H ₂ O	5 A g ⁻¹ , maximum capacity up to 133.4 mA h g ⁻¹	1
V ₃ O ₇ ·H ₂ O	5 A g ⁻¹ , 171.6 mA h g ⁻¹ after 1000 cycles, 85%	2
CuV ₂ O ₆	5 A g ⁻¹ , 143 mA h g ⁻¹ after 1200 cycles	3
Od-HVO/rG	5 A g ⁻¹ , 276 mA h g ⁻¹ after 750 cycles, 119.4%	4
H ₁₁ Al ₂ V ₆ O _{23.2}	5 A g ⁻¹ , 141 mA h g ⁻¹ after 7000 cycles, 118% of the initial capacity	5
Cr _{0.09} V ₂ O ₅ (H ₂ O) ₂ ·H ₂ O	5 A g ⁻¹ , 205 mA h g ⁻¹ after 1000 cycles, 96%	6

Table S5. Charge/discharge of MgVO III corresponds to EDX

Operational status	Element	Weight (%)	Atom (%)
Discharge	Mg	0.13	0.11
	V	4.07	1.63
	Zn	26.13	8.17
Charge	Mg	0.08	0.05
	V	22.44	7.33
	Zn	3.29	0.84

Notes and references:

1. S. Luo, X. Cao, Q. Su, Y. Zhang, S. Liu, X. Xie, S. Liang and A. Pan, ACS Applied Energy Materials, 2021, 4, 6197-6204.
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